

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

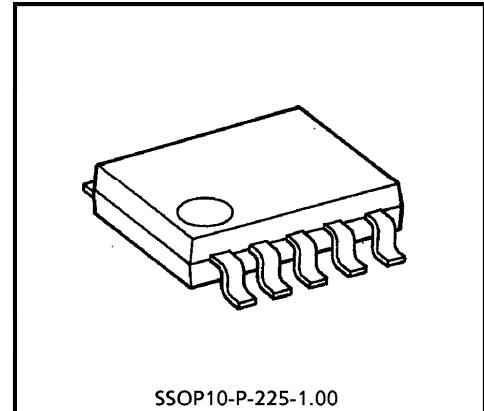
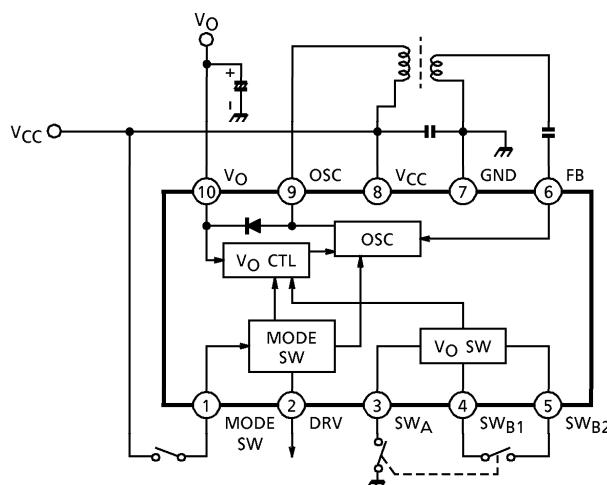
**TA8161F****DC / DC CONVERTER SYSTEM IC FOR POWER SUPPLY**

The TA8161F is a DC/DC converter system IC, which is developed for supplying a voltage (for 2.5V or 5V) for CMOS IC etc.

It is especially suitable for low voltage operation, and for power supply and back-up of speech recording / playback LSIs, with only one or two dry batteries.

**FEATURES**

- Output voltage can be switched over to 2.5V or 5V  
( $V_O = 2.5V$  mode (by one dry-battery)  
  ( $V_O = 5V$  mode (by one or two dry-batteries))
- Built-in backup mode with a very low power dissipation  
 $V_{CC} = 1.2V$ ,  $T_a = 25^\circ C$ ,  $I_O = 0$   
( $I_{CC1} = 50\mu A$  (Typ.) .....  $V_O = 5V$  mode  
  ( $I_{CC2} = 30\mu A$  (Typ.) .....  $V_O = 2.5V$  mode)
- Built-in mode switch (Back up mode / Power supply mode)
- Excellent power efficiency, by blocking oscillation
- Output current ( $V_{CC} = 1.2V$ ,  $T_a = 25^\circ C$ )  
 $I_O1 = 11mA$  (Typ.) .....  $V_O = 5V$  mode  
 $I_O2 = 22mA$  (Typ.) .....  $V_O = 2.5V$  mode
- Operating supply voltage range ( $T_a = 25^\circ C$ )  
 $V_{CC2} (\text{opr}) = 0.9 \sim 4V$  ( $V_O = 5V$  mode)  
 $V_{CC1} (\text{opr}) = 0.9 \sim 2.2V$  ( $V_O = 2.5V$  mode)

**BLOCK DIAGRAM**

SSOP10-P-225-1.00

Weight : 0.09g (Typ.)

● TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

961001EBA2

## TERMINAL EXPLANATION

TERMINAL		FUNCTION	INTERNAL CIRCUIT									
No.	NAME											
1	MODE SW	Mode switch [ V <sub>CC</sub> : Power supply mode GND / open : Back up mode ]										
2	DRV	Current driver This terminal can be used for current driver, because it is synchronized with mode switch. In case that this circuit isn't used, this terminal should be connected with SW <sub>B2</sub> (Pin⑤) terminal, as a result low voltage operation is improved.										
3	SW <sub>A</sub>	Change-over switch of output voltage.										
4	SW <sub>B1</sub>	<table border="1"> <tr> <th></th> <th>SW<sub>1a</sub></th> <th>SW<sub>1b</sub></th> </tr> <tr> <td>5V mode</td> <td>Open</td> <td></td> </tr> <tr> <td>2.5V mode</td> <td>Short</td> <td></td> </tr> </table> To prevent parasitic oscillation, external capacitor should be connected between SW <sub>B1</sub> and V <sub>CC</sub> . Because the SW <sub>B1</sub> terminal is high impedance.		SW <sub>1a</sub>	SW <sub>1b</sub>	5V mode	Open		2.5V mode	Short		
	SW <sub>1a</sub>	SW <sub>1b</sub>										
5V mode	Open											
2.5V mode	Short											
5	SW <sub>B2</sub>											
6	FB											
9	OSC	Flyback converter										
10	V <sub>O</sub>											
7	GND	—	—									
8	V <sub>CC</sub>	—	—									

961001EBA2'

- The products described in this document are subject to foreign exchange and foreign trade control laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.

**APPLICATION NOTE****1. MODE EXPLANATION**

IC MODE	VO SW		MODE SW	CURRENT DRIVER Pin②	
	SW1A	SW1B	SW2		
VO = 2.5V	Power Supply Mode	GND	Short	V <sub>CC</sub>	ON
	Back Up Mode			Open / GND	OFF
VO = 5V	Power Supply Mode	Open	Open	V <sub>CC</sub>	ON
	Back Up Mode			Open / GND	OFF

**2. OPERATION OF BACK UP MODE**

In case of back up mode, this IC is operated by blocking oscillation. This operation is described as follows.

- (1) When potential of output VO reaches V<sub>TH</sub>(L), the VO control circuit in the IC starts the converter circuit.
- (2) When the converter is started, the capacitor C connected with VO terminal is charged and when VO reaches V<sub>TH</sub>(H), the converter is stopped.
- (3) The charge of the capacitor C is consumed gradually by load current and comes close to V<sub>TH</sub>(L). This IC is performs the blocking oscillation by repeating (1)~(3) above. The frequency of this blocking oscillation depends on load current and a capacitor connected with VO terminal.

**3. MODE SW**

It is necessary to connect an external pull-down resistor with the terminal of MODE SW (pin①), in case that this IC operates in power supply mode due to external noise etc, even though this IC is back up mode.

**4. CURRENT DRIVER TERMINAL**

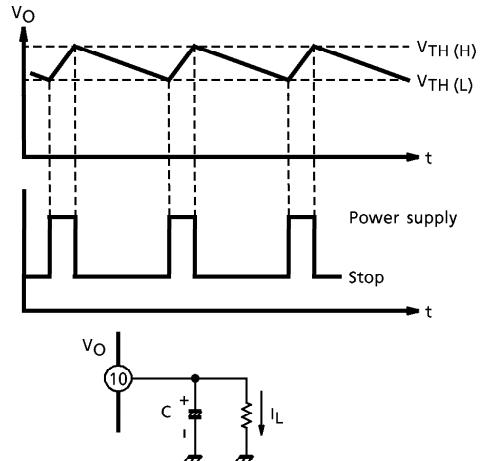
In case that current driver terminal (pin②) isn't used, this terminal should be connected with SW<sub>B2</sub> terminal (pin⑤), as a result low voltage operation is improved. When this terminal is kept open, there is a probability that the MODE SW circuit doesn't operate normally.

**5. RADIATION**

It is necessary to connect a L/C or R/C filter, in case that output noise is large due to radiation etc. Because this IC has adopted a converter circuit of flyback system.

**6. VO and V<sub>CC</sub>**

Supply voltage should not be high than output voltage, because this IC is boost type DC/DC converter.



MAXIMUM RATINGS ( $T_a = 25^\circ\text{C}$ )

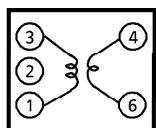
CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	$V_{CC}$	5	V
Output Voltage	$V_O$	8	V
Output Current	$I_O$	40	mA
Power Dissipation	$P_D$ (Note)	400	mW
Operating Temperature	$T_{opr}$	-25~75	°C
Storage Temperature	$T_{stg}$	-55~150	°C

(Note) Derated above  $T_a = 25^\circ\text{C}$  in the proportion of  $3.2\text{mW}/^\circ\text{C}$ .ELECTRICAL CHARACTERISTICS (Unless otherwise specified,  $V_{CC} = 1.2\text{V}$ ,  $T_a = 25^\circ\text{C}$ ,  $SW_2 : a$ ,  $SW_3 : a$ )

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Power Supply Mode	Quiescent Supply Current	$I_{CC01}$	a	$I_O = 0$	—	0.5	1.0	mA
		$I_{CC02}$			—	0.3	0.8	
	Boosted Output Voltage 1	$V_{O11}$	a	$I_O = 5\text{mA}$	4.6	5.0	5.3	V
		$V_{O12}$		$I_O = 5\text{mA}, V_{CC} = 1\text{V}$	4.6	5.0	5.3	
	$V_{O1}$ Temperature Coefficient	$\Delta V_{O1}/T$		$I_O = 5\text{mA}$	—	-4.4	—	
	$V_{O1}$ Maximum Output Current	$I_{O1 \text{ max}1}$		$V_{CC} = 1.2\text{V}$	8	11	—	mA
		$I_{O1 \text{ max}2}$		$V_{CC} = 1.5\text{V}$	10	17	—	
	Boosted Output Voltage 2	$V_{O21}$	b	$I_O = 10\text{mA}$	2.2	2.5	2.8	V
		$V_{O22}$		$V_{CC} = 1\text{V}, I_O = 10\text{mA}$	2.2	2.5	2.8	
	$V_{O2}$ Temperature Coefficient	$\Delta V_{O2}/T$		$I_O = 10\text{mA}$	—	-4.6	—	mV / °C
	$V_{O2}$ Maximum Output Current	$I_{O2 \text{ max}}$		$\Delta V_{O2} = 0.3\text{V}$ , with respect to standard $I_{O2} = 10\text{mA}$	16	22	—	
Back Up Mode	Quiescent Supply Current	$I_{BU1}$	a	$SW_2 : b, I_O = 0$	—	50	—	$\mu\text{A}$
		$I_{BU2}$			—	30	—	
	OSC Start Output Voltage 1	$V_{TH11}$	a	$SW_2 : b, I_O = 0$	4.0	4.3	4.6	V
	OSC Stop Output Voltage 1	$V_{TH12}$			4.6	5.0	5.3	
	OSC Start Output Voltage 2	$V_{TH21}$	b	$SW_2 : b, I_O = 0$	1.8	2.2	2.4	V
	OSC Stop Output Voltage 2	$V_{TH22}$			2.2	2.5	2.7	
MODE SW	OSC Transistor Saturation Voltage	$V_{DRV}$	b	$V_{CC} = 0.9\text{V}, SW_3 : b$ $I_{DRV} = 0.5\text{mA}$	—	50	150	mV
	Power Supply Mode On Current	$I_{mode}$	b	$V_{CC} = 0.9\text{V}, SW_2 : c$ $SW_3 : b$ $V_{O1} \geq 2\text{V}, V_{DRV} \leq 50\text{mV}$	10	—	—	$\mu\text{A}$
	Back Up Mode On Voltage	$V_{mode}$	b	$V_{CC} = 0.9\text{V}, SW_2 : d$ $SW_3 : b$ $V_{DRV} \geq 0.8\text{V}$	0	—	0.3	V

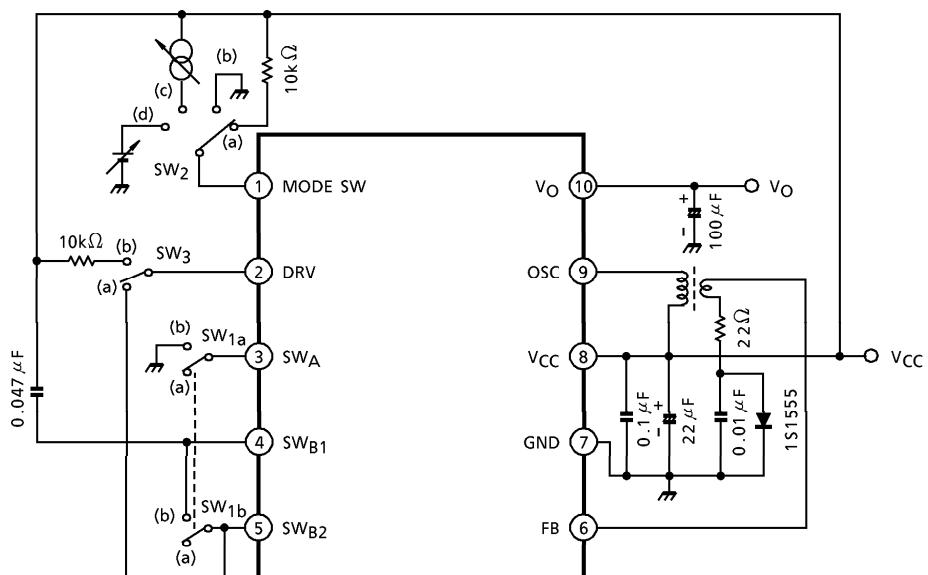
## COIL DATA

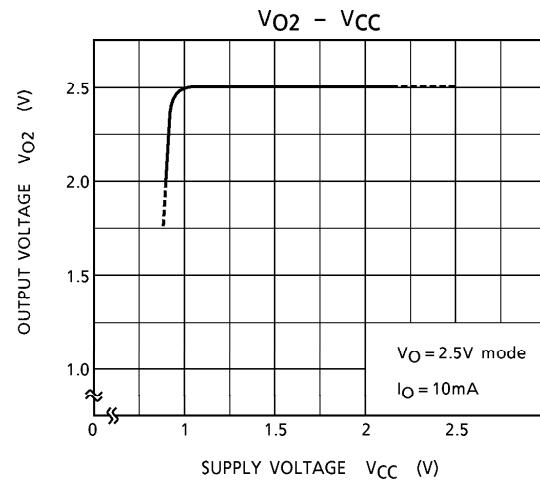
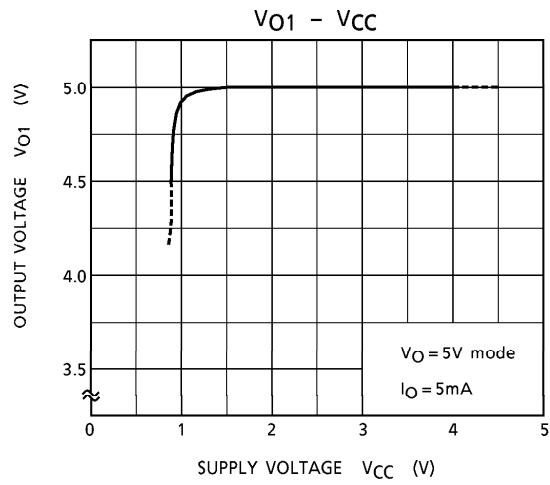
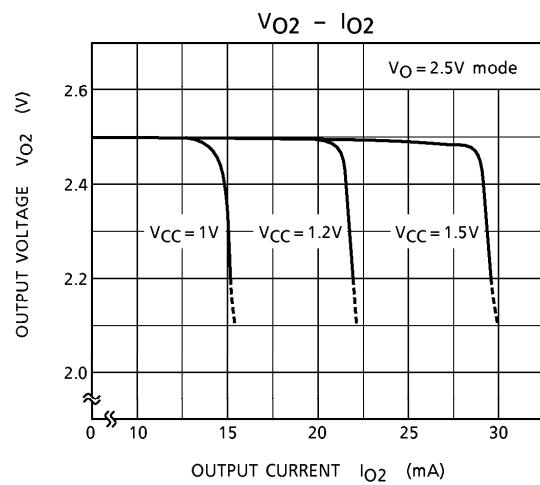
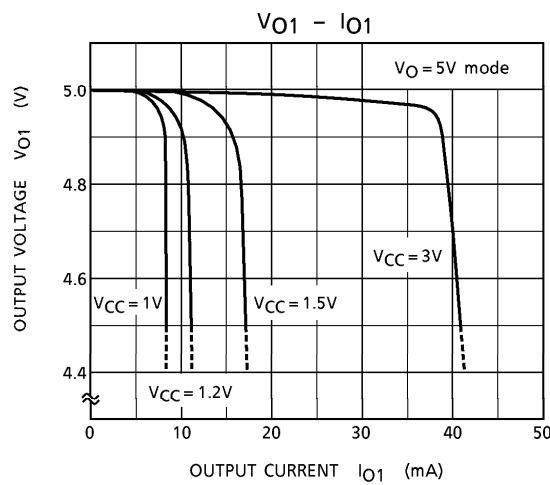
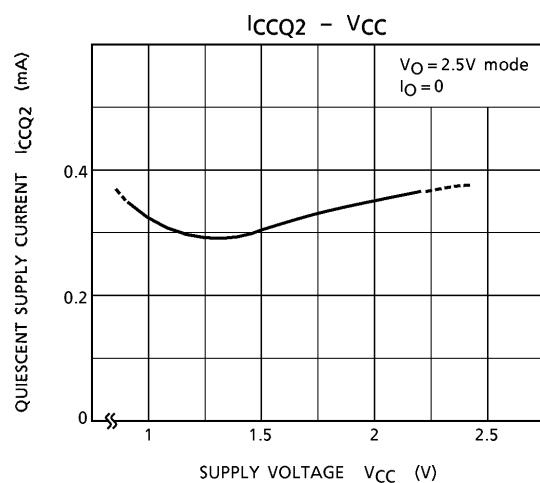
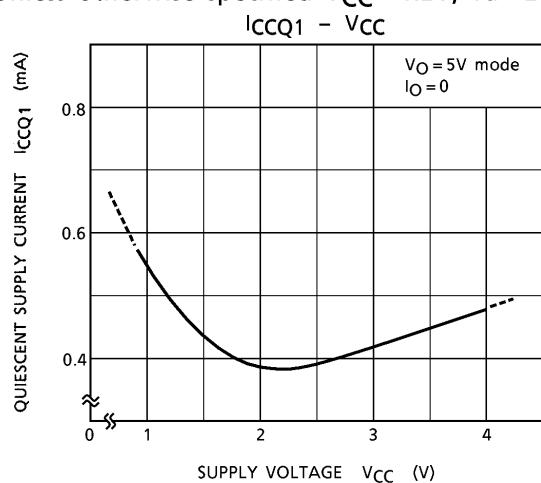
TEST FREQUENCY	L ( $\mu\text{H}$ )	$Q_0$	TURN		WIRE (mm $\phi$ )	REFERENCE
	1-3	1-3	4-6			
796kHz	200	35	72	42	0.10UEW	SUMIDA ELECTRIC Co., Ltd, 6300-131A

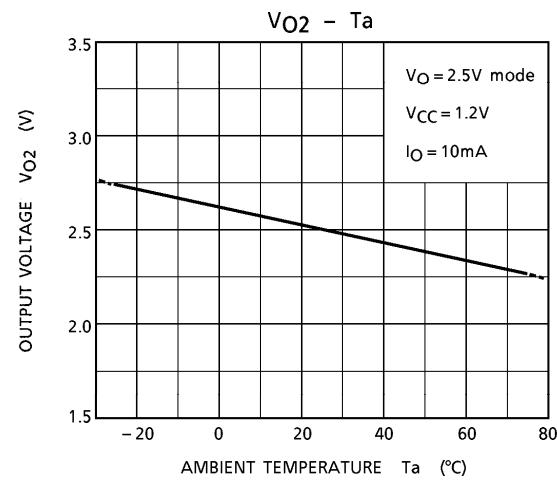
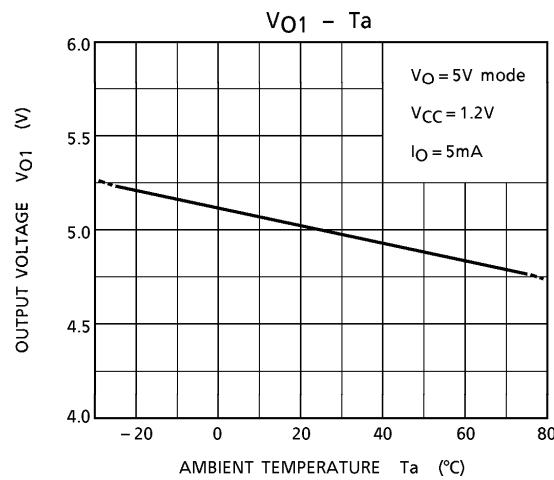
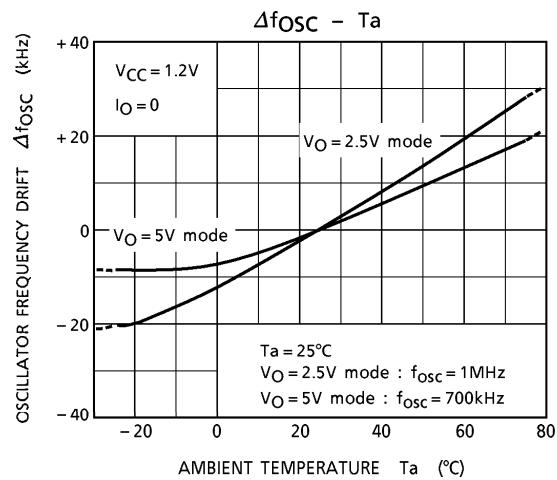
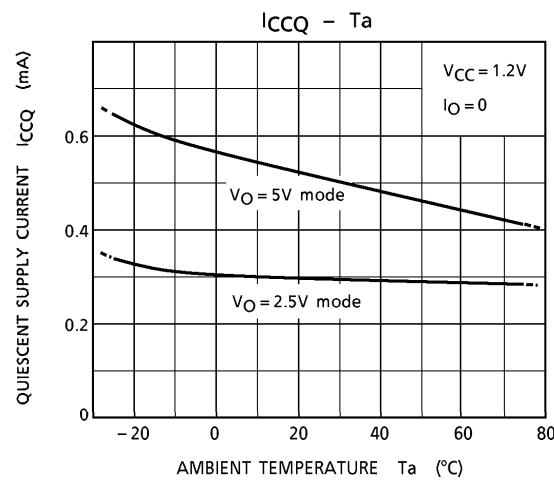
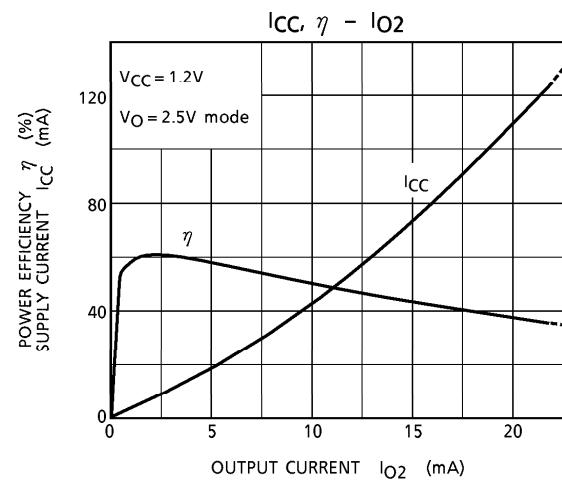
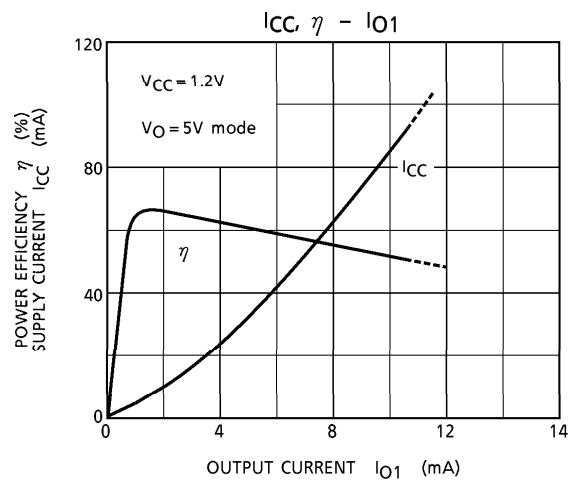


(Bottom of view)

## TEST CIRCUIT



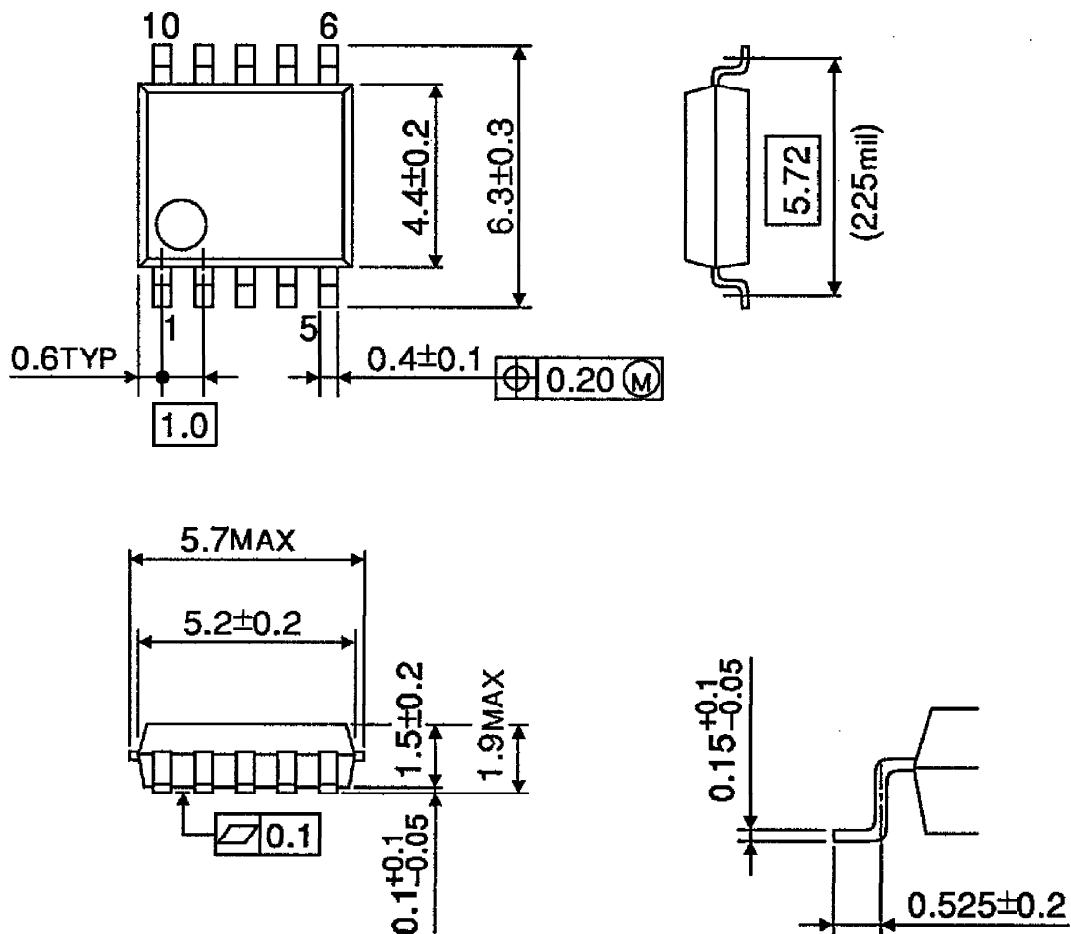
**CHARACTERISTIC CURVES**Unless otherwise specified  $V_{CC} = 1.2V$ ,  $T_a = 25^\circ C$ ,  $I_O = 0$ 



## OUTLINE DRAWING

SSOP10-P-225-1.00

Unit : mm



Weight : 0.09g (Typ.)

Copyright Each Manufacturing Company.

All Datasheets cannot be modified without permission.

This datasheet has been download from :

[www.AllDataSheet.com](http://www.AllDataSheet.com)

100% Free DataSheet Search Site.

Free Download.

No Register.

Fast Search System.

[www.AllDataSheet.com](http://www.AllDataSheet.com)